

Features

- 200MHz -3dB bandwidth, $A_V = 2$
- Disable/enable
- 12ns settling to 0.05%
- $V_S = \pm 5V @ 15mA$
- Low distortion: HD2, HD3 @ -60dBc at 20MHz
- Differential gain 0.02% at NTSC, PAL
- Differential phase 0.01° at NTSC, PAL
- Overload/short-circuit protected
- ± 1 to ± 8 closed-loop gain range
- Low cost

Applications

- Video gain block
- Video distribution
- HDTV amplifier
- Analog multiplexing (using disable)
- Power-down mode (using disable)
- High-speed A/D conversion
- D/A I-V conversion
- Photodiode, CCD preamps
- IF processors
- High-speed communications

Ordering Information

Part No.	Package	Tape & Reel	Outline #
EL2070CN	PDIP-8	-	MDP0031
EL2070CS	SO-8	-	MDP0027
EL2070CS-T7	SO-8	7 in	MDP0027
EL2070CS-T13	SO-8	13 in	MDP0027

General Description

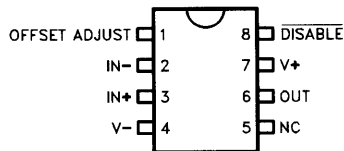
The EL2070C is a wide bandwidth, fast settling monolithic amplifier incorporating a disable/enable feature. Built using an advanced complementary bipolar process, this amplifier uses current-mode feedback to achieve more bandwidth at a given gain than conventional operational amplifiers. Designed for closed-loop gains of ± 1 to ± 8 , the EL2070C has a 200MHz -3dB bandwidth ($A_V = +2$), and 12ns settling to 0.05% while consuming only 15mA of supply current. Furthermore, the fast disable/enable times of 200ns/100ns allow rapid analog multiplexing.

The EL2070C is an obvious high-performance solution for video distribution and line-driving applications, especially when its disable feature can be used for fast analog multiplexing. Furthermore, the low 15mA supply current, and the very low 5mA of supply current when disabled suggest use in systems where power is critical. With differential gain/phase of 0.02%/0.01°, guaranteed video specifications, and a minimum 50mA output drive, performance in these areas is assured.

The EL2070C's settling to 0.05% in 12ns, low distortion, and ability to drive capacitive loads make it an ideal flash A/D driver. The wide 200MHz bandwidth and extremely linear phase allow unmatched signal fidelity. D/A systems can also benefit from the EL2070C, especially if linearity and drive levels are important.

Connection Diagrams

DIP and SO Package - Top View



Manufactured under U.S. Patent No. 4,893,091

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$)

Supply Voltage (V_S)	$\pm 7\text{V}$	$\theta_{JA} = 175^\circ\text{C/W SO-8}$
Output Current	70mA	Applied Output Voltage (Disabled) $\pm V_S$
(Output is short-circuit protected to ground, however, maximum reliability is obtained if I_{OUT} does not exceed 70mA)		Power Dissipation See Curves
Common-Mode Input Voltage	$\pm V_S$	Operating Temperature EL2070C -40°C to +85°C
Differential Input Voltage	5V	Lead Temperature (Soldering, 5 Seconds) 300°C
Disable Input Voltage	$+V_S, -1\text{V}$	Junction Temperature 175°C
Thermal Resistance	$\theta_{JA} = 95^\circ\text{C/W PDIP}$	Storage Temperature -60°C to +150°C

Important Note:

All parameters having Min/Max specifications are guaranteed. Typ values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Open Loop DC Electrical Characteristics

$V_S = \pm 5\text{V}$, $R_L = 100\Omega$ unless otherwise specified

Parameter	Description	Test Conditions	Temp	Min	Typ	Max	Units
V_{OS}	Input Offset Voltage		25°C		2	5.5	mV
			T_{MIN}			8.2	mV
			T_{MAX}			9.0	mV
$d(V_{OS})/dT$	Average Offset Voltage Drift	[1]	All	10.0	40.0	$\mu\text{V}/^\circ\text{C}$	
$+I_{IN}$	+Input Current		25°C, T_{MAX}	10	25.0	μA	
			T_{MIN}		36.0	μA	
$d(+I_{IN})/dT$	Average +Input Current Drift	[1]	All	50.0	200.0	$\text{nA}/^\circ\text{C}$	
$-I_{IN}$	-Input Current		25.0°C	10	30	μA	
			T_{MIN}, T_{MAX}		46	μA	
$d(-I_{IN})/dT$	Average -Input Current Drift	[1]	All	50.0	200.0	$\text{nA}/^\circ\text{C}$	
PSRR	Power Supply Rejection Ratio		All	45.0	50.0	dB	
CMRR	Common-Mode Rejection Ratio		All	40.0	50.0	dB	
I_S	Supply Current—Quiescent	No Load	All	16.0	20.0	mA	
I_{SOFF}	Supply Current—Disabled	[2]	All	4.0	7.0	mA	
$+R_{IN}$	+Input Resistance		25°C, T_{MAX}	100.0	200.0	k Ω	
			T_{MIN}	50.0		k Ω	
C_{IN}	Input Capacitance		All	0.5	2.0	pF	
R_{OUT}	Output Impedance (DC)		All	0.1	0.2	Ω	
R_{OUTD}	Output Resistance (DC)	Disabled	All	100.0	200.0	k Ω	
C_{OUTD}	Output Capacitance (DC)	Disabled	All	0.5	2.0	pF	
CMIR	Common-Mode Input Range	[3]	25°C, T_{MAX}	2.0	2.1	V	
			T_{MIN}	1.2		V	
I_{OUT}	Output Current		25°C, T_{MAX}	50.0	70.0	mA	
			T_{MIN}	35.0		mA	
V_{OUT}	Output Voltage Swing	No Load	All	3.3	3.5	V	
V_{OUTL}	Output Voltage Swing	100 Ω	25°C	3.0	3.4	V	

EL2070C**200MHz Current Feedback Amplifier****Open Loop DC Electrical Characteristics (Continued)** $V_S = \pm 5V$, $R_L = 100\Omega$ unless otherwise specified

Parameter	Description	Test Conditions	Temp	Min	Typ	Max	Units
-ICMR	Input Current Common Mode Rejection		25°C		8.0	33.0	$\mu A/V$
+IPSR	+Input Current Power Supply Rejection		25°C		1.0	3.6	$\mu A/V$
-IPSR	-Input Current Power Supply Rejection		25°C		20	24	$\mu A/V$
R_{OL}	Transimpedance		25°C	30.0	125.0		V/mA
			T_{MIN}		80.0		V/mA
			T_{MAX}		140.0		V/mA
I_{LOGIC}	Pin 8 Current @ 0V		All		0.8	1.2	mA
V_{DIS}	Maximum Pin 8 V to Disable		All			0.5	V
V_{EN}	Minimum Pin 8 V to Enable		All	3.5			V
I_{DIS}	Minimum Pin 8 I to Disable		All	350.0			μA
I_{EN}	Maximum Pin 8 I to Enable		All			60.0	μA

1. Measured from T_{MIN} to T_{MAX} .
2. Supply current when disabled is measured at the negative supply.
3. Common-mode input range for rated performance.

Closed-Loop AC Electrical Characteristics $V_S = \pm 5V$, $R_F = 250\Omega$, $A_V = +2$, $R_L = 100\Omega$ unless otherwise specified

Parameter	Description	Test Conditions	Temp	Min	Typ	Max	Units
FREQUENCY RESPONSE							
SSBW	-3dB Bandwidth ($V_{OUT} < 0.5V_{PP}$)		25°C	150.0	200.0		MHz
			T_{MIN}	150.0			MHz
			T_{MAX}	120.0			MHz
LSBW	-3dB Bandwidth ($V_{OUT} < 5.0V_{PP}$)	$A_V = +5$	All	35.0	50.0		MHz
GAIN FLATNESS							
GFPL	Peaking $V_{OUT} < 0.5V_{PP}$	<40MHz	25°C		0.0	0.3	dB
			T_{MIN}, T_{MAX}			0.4	dB
GFPH	Peaking $V_{OUT} < 0.5V_{PP}$	>40MHz	25°C		0.0	0.5	dB
			T_{MIN}, T_{MAX}			0.7	dB
GFR	Rolloff $V_{OUT} < 0.5V_{PP}$	<75MHz	25°C		0.6	1.0	dB
			T_{MIN}			1.0	dB
			T_{MAX}			1.3	dB
LPD	Linear Phase Deviation $V_{OUT} < 0.5V_{PP}$	<75MHz	25°C, T_{MIN}		0.2	1.0	°
			T_{MAX}			1.2	°
TIME-DOMAIN RESPONSE							
t_{r1}, t_{f1}	Rise Time, Fall Time	0.5V Step	All		1.6	2.4	ns

Closed-Loop AC Electrical Characteristics

$V_S = \pm 5V$, $R_F = 250\Omega$, $A_V = +2$, $R_L = 100\Omega$ unless otherwise specified

Parameter	Description	Test Conditions	Temp	Min	Typ	Max	Units
t_{r2}, t_{f2}	Rise Time, Fall Time	5.0V Step	All		6.5	10.0	ns
t_{s1}	Settling Time to 0.1%	2.0V Step	All		10.0	13.0	ns
t_{s2}	Settling Time to 0.05%	2.0V Step	All		12.0	15.0	ns
OS	Overshoot	0.5V Step	25°C, T_{MAX}		0.0	10.0	%
			T_{MIN}			15.0	%
SR	Slew Rate	$A_V = +2$	All	430.0	700.0		V/ μ s
		$A_V = -2$	All		1600.0		V/ μ s

DISTORTION

HD2	2nd Harmonic Distortion at 20MHz	2V _{pp}	25°C		-60.0	-45.0	dBc
			T_{MIN}			-40.0	dBc
			T_{MAX}			-45.0	dBc
HD3	3rd Harmonic Distortion at 20MHz	2V _{pp}	25°C		-60.0	-50.0	dBc
			T_{MIN}, T_{MAX}			-50.0	dBc

EQUIVALENT INPUT NOISE

NF	Noise Floor >100kHz	[1]	25°C		-157.0	-154.0	dBm (1Hz)
			T_{MIN}			-154.0	dBm (1Hz)
			T_{MAX}			-153.0IV	dBm (1Hz)
INV	Integrated Noise 100kHz to 200MHz	[1]	25°C		40.0	57.0	μ V
			T_{MIN}			57.0	μ V
			T_{MAX}			63.0	μ V

DISABLE/ENABLE PERFORMANCE

T_{OFF}	Disable Time to >50dB	10MHz	All		1000.0	IV	ns
T_{ON}	Enable Time		All		200.0		ns
OFFIso	Off Isolation	10MHz	All	55.0	59.0		dB

VIDEO PERFORMANCE

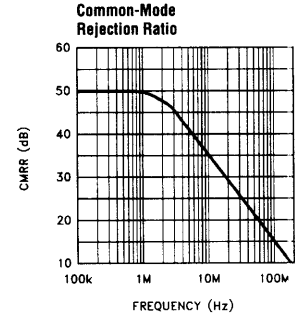
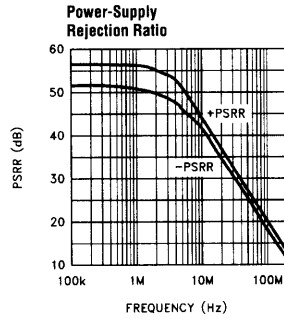
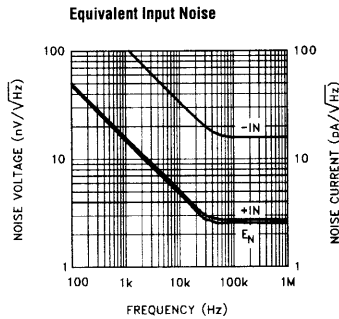
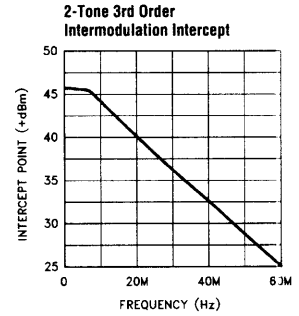
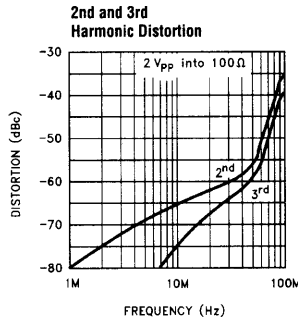
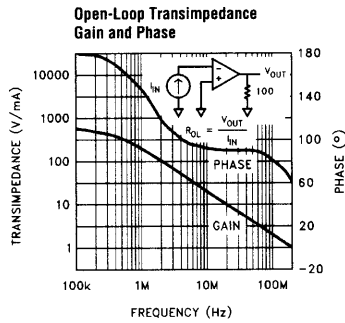
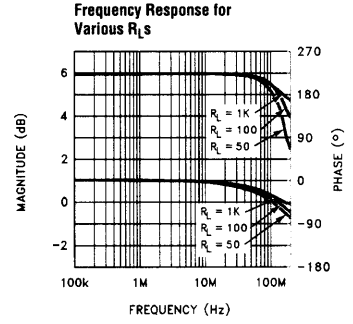
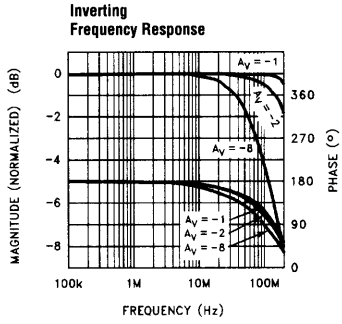
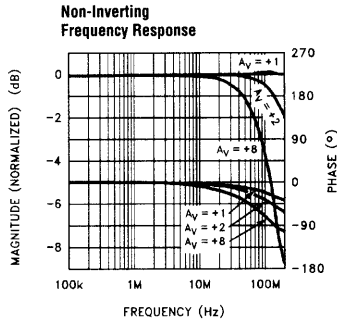
d_G	Differential Gain [2]	NTSC/PAL	25°C		0.02	0.08	% pp
d_P	Differential Phase [2]	NTSC/PAL	25°C		0.01	0.08	° pp
d_G	Differential Gain [2]	30MHz	25°C		0.05	0.18	% pp
d_P	Differential Phase [2]	30MHz	25°C		0.05	0.18	° pp
VBW	-0.1dB Bandwidth [2]		25°C	30.0	60.0		MHz

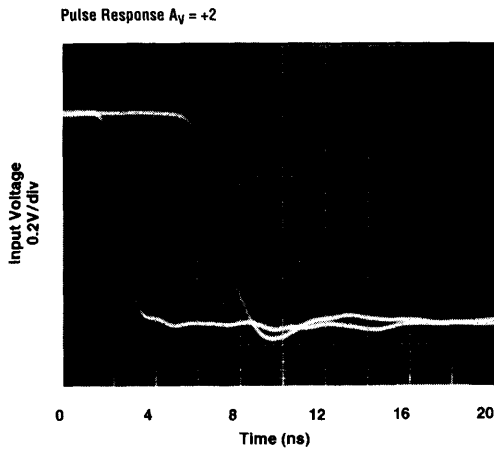
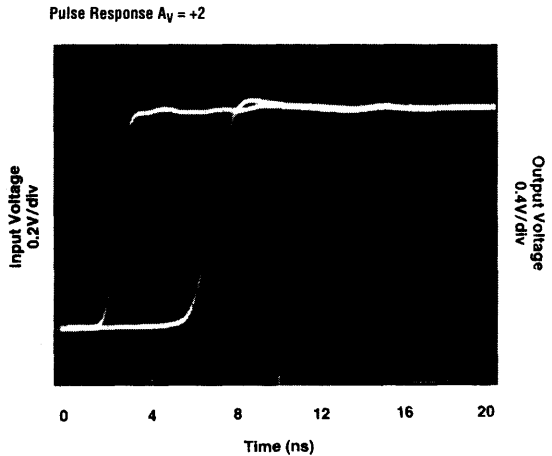
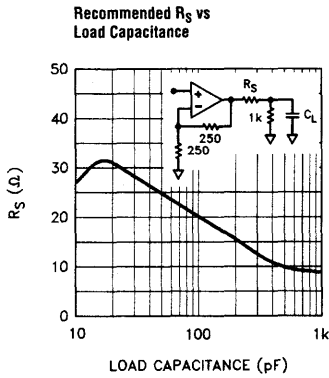
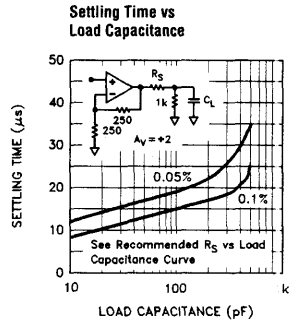
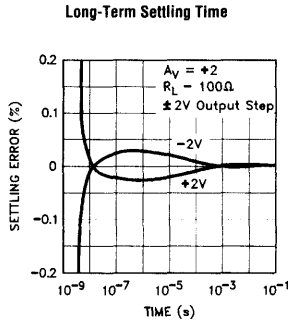
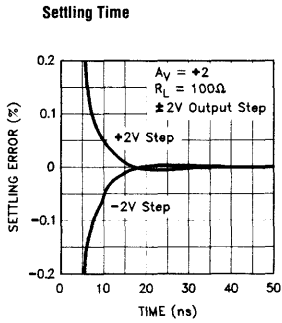
- Noise Tests are performed from 5MHz to 200MHz.
- Differential gain/phase tests are with $R_L = 100\Omega$. For other values of R_L , see curves.

EL2070C

200MHz Current Feedback Amplifier

Typical Performance Curves

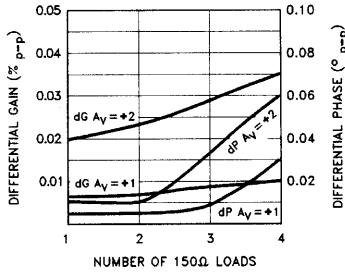




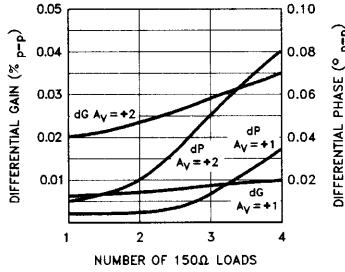
EL2070C

200MHz Current Feedback Amplifier

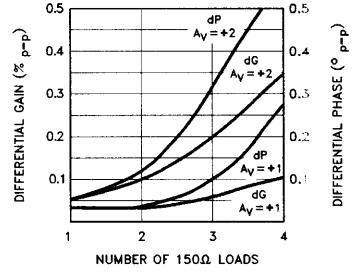
Differential Gain and Phase (3.58MHz)



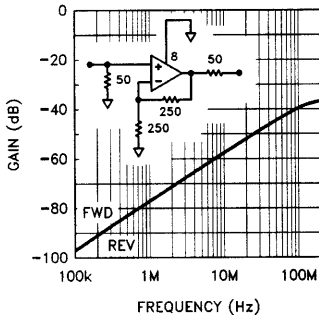
Differential Gain and Phase (4.43MHz)



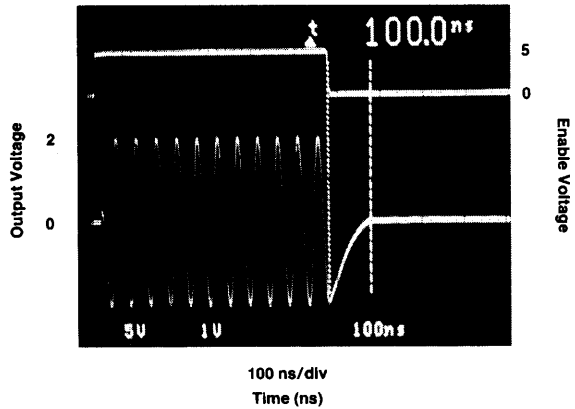
Differential Gain and Phase (30MHz)



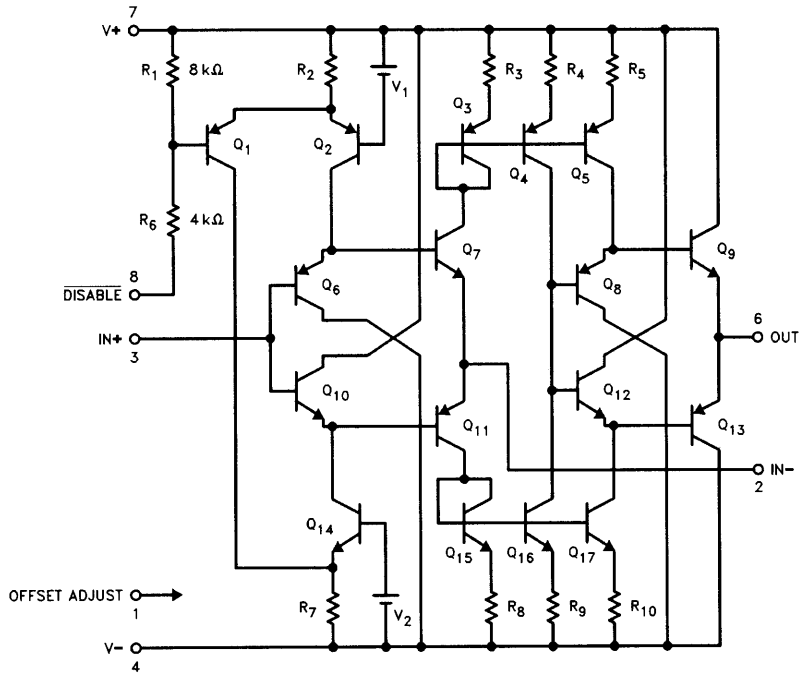
Forward and Reverse Gain during Disable



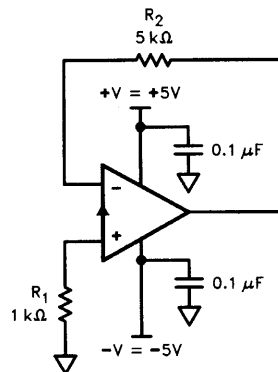
Enable/Disable Response



Equivalent Circuit



Burn-In Circuit



ALL PACKAGES USE THE SAME SCHEMATIC.

EL2070C

200MHz Current Feedback Amplifier

Applications Information

Theory of Operation

The EL2070C has a unity gain buffer from the non-inverting input to the inverting input. The error signal of the EL2070C is a current flowing into (or out of) the inverting input. A very small change in current flowing through the inverting input will cause a large change in the output voltage. This current amplification is called the transimpedance (R_{OL}) of the EL2070C [$V_{OUT} = (R_{OL}) * (-I_{IN})$]. Since R_{OL} is very large, the current flowing into the inverting input in the steady-state (non-slewing) condition is very small.

Therefore we can still use op-amp assumptions as a first-order approximation for circuit analysis, namely that:

1. The voltage across the inputs is approximately 0V.
2. The current into the inputs is approximately 0mA.

Resistor Value Selection and Optimization

The value of the feedback resistor (and an internal capacitor) sets the AC dynamics of the EL2070C. The nominal value for the feedback resistor is 250 Ω , which is the value used for production testing. This value guarantees stability. For a given closed-loop gain the bandwidth may be increased by decreasing the feedback resistor and, conversely, the bandwidth may be decreased by increasing the feedback resistor.

Reducing the feedback resistor too much will result in overshoot and ringing and eventually oscillations. Increasing the feedback resistor results in a lower -3dB frequency. Attenuation at high frequency is limited by a zero in the closed-loop transfer function which results from stray capacitance between the inverting input and ground. Consequently, it is very important to keep stray capacitance to a minimum at the inverting input.

Differential Gain/Phase

An industry-standard method of measuring the distortion of a video component is to measure the amount of differential gain and phase error it introduces. To measure these, a 40 IRE_{pp} reference signal is applied to the device with 0V DC offset (0 IRE) at 3.58MHz for NTSC, 4.43MHz for PAL, and 30MHz for HDTV. A

second measurement is then made with a 0.714V DC offset (100IRE). Differential Gain is a measure of the change in amplitude of the sine wave, and is measured in percent. Differential Phase is a measure of the change in phase, and is measured in degrees. Typically, the maximum positive and negative deviations are summed to give peak values.

In general, a back terminated cable (75 Ω in series at the drive end and 75 Ω to ground at the receiving end) is preferred since the impedance match at both ends will absorb any reflections. However, when double-termination is used, the received signal is reduced by half; therefore a gain of 2 configuration is typically used to compensate for the attenuation. In a gain of 2 configuration, with output swing of 2V_{pp}, with each back-terminated load at 150 Ω . The EL2070C is capable of driving up to 4 back-terminated loads with excellent video performance. Please refer to the typical curves for more information on video performance with respect to frequency, gain, and loading.

Capacitive Feedback

The EL2070C relies on its feedback resistor for proper compensation. A reduction of the impedance of the feedback element results in less stability, eventually resulting in oscillation. Therefore, circuit implementations which have capacitive feedback should not be used because of the capacitor's impedance reduction with frequency. Similarly, oscillations can occur when using the technique of placing a capacitor in parallel with the feedback resistor to compensate for shunt capacitances from the inverting input to ground.

Offset Adjustment Pin

Output offset voltage of the EL2070C can be nulled by tying a 10k potentiometer between +V_S and -V_S with the slider attached to pin 1. A full-range variation of the voltage at pin 1 to $\pm 5V$ results in an offset voltage adjustment of at least $\pm 10mV$. For best settling performance pin 1 should be bypassed to ground with a ceramic capacitor located near to the package, even if the offset voltage adjustment feature is not being used.

Printed Circuit Layout

As with any high frequency device, good PCB layout is necessary for optimum performance. Ground plane construction is a requirement, as is good power-supply and Offset Adjust bypassing close to the package. The inverting input is sensitive to stray capacitance, therefore connections at the inverting input should be minimal, close to the package, and constructed with as little coupling to the ground plane as possible.

Capacitance at the output node will reduce stability, eventually resulting in peaking, and finally oscillation if the capacitance is large enough. The design of the EL2070C allows a larger capacitive load than comparable products, yet there are occasions when a series resistor before the capacitance may be needed. Please refer to the graphs to determine the proper resistor value needed.

Disable/Enable Operation

The EL2070C has a disable/enable control input at pin 8. The device is enabled and operates normally when pin 8 is left open or tied to pin 7. When more than 350 μ A is pulled from pin 8, the EL2070C is disabled. The output becomes a high impedance, the inverting input is no longer driven to the positive input voltage, and the supply current is reduced by 2/3. To make it easy to use this feature, there is an internal resistor to limit the current to a safe level (0.8mA) if pin 8 is grounded.

To draw current out of pin 8 an open-collector TTL output, a 5V CMOS output, or an NPN transistor can be used.

EL2070C

200MHz Current Feedback Amplifier

EL2070 Macromodel

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* Revision A. March 1992
* Enhancements include PSRR, CMRR, and Slew Rate Limiting
* Connections:  +input
*               |
*               | -input
*               |
*               | +Vsupply
*               | |
*               | | -Vsupply
*               | |
*               | | output
*               | |
.subckt M2070 3 2 7 4 6
*
* Input Stage
*
e1 10 0 3 0 1.0
vis 10 9 0 V
h2 9 12 vxx 1.0
r1 2 11 50
l1 11 12 48 nH
iinp 3 0 8  $\mu$ A
iinm 2 0 8  $\mu$ A
*
* Slew Rate Limiting
*
h1 13 0 vis 600
r2 13 14 1 K
d1 14 0 dclamp
d2 0 14 dclamp
*
* High Frequency Pole
*
e2 30 0 14 0 0.001666666666
l3 30 17 0.1  $\mu$ H
c5 17 0 0.1 pF
r5 17 0 500
*
* Transimpedance Stage
*
g1 0 18 17 0 1.0
rol 18 0 150 K
cdp 18 0 2.8 pF
*
* Output Stage
*
q1 4 18 19 qp
q2 7 18 20 qn
q3 7 19 21 qn
q4 4 20 22 qp
r7 21 6 2
r8 22 6 2

ios1 7 19 2.5 mA
ios2 20 4 2.5 mA
*
* Supply Current
*
ips 7 4 9 mA
*
* Error Terms
*
ivos 0 23 5 mA
vxx 23 0 0 V
e4 24 0 3 0 1.0
e5 25 0 7 0 1.0

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```
e6 26 0 4 0 1.0
r9 24 23 3 K
r10 25 23 1 K
r11 26 23 1 K
*
* Models
*
.model qn npn (is=5e-15 bf=200 tf=0.05nS)
.model qp pnp (is=5e-15 bf=200 tf=0.05nS)
.model dclamp d(is=1e-30 ibv=0.266 bv=1.3 n=4)
.ends
```

EL2070C

200MHz Current Feedback Amplifier

EL2070 Macromodel

